



Product Summary

BVDSS	Rds(on)	Package	Ι _D T _C = +25°C
100V	$8.8m\Omega @V_{GS} = 10V$	TO220AB	99A
1000	$16m\Omega @V_{GS} = 6V$	TOZZUAD	73A

Description

This new generation MOSFET features low on-resistance and fast switching, making it ideal for high-efficiency power management applications.

Applications

- Motor Control
- Backlighting
- DC-DC Converters
- Power Management Functions

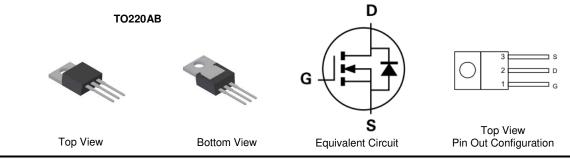
100V N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low Input Capacitance
- High BVDSS Rating for Power Application
- Low Input/Output Leakage
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: TO220AB
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208
 ⁽³⁾
- Terminal Connections: See Diagram Below
- Weight: TO220AB 1.85 grams (Approximate)



Ordering Information (Note 4)

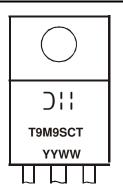
Part Number	Case	Packaging
DMT10H9M9SCT	TO220AB	50 Pieces/Tube

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage	VDSS	100	V	
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current (Note 6) V_{GS} = 10V	$T_{C} = +25^{\circ}C$ $T_{C} = +70^{\circ}C$	ID	99 79	А
Maximum Continuous Body Diode Forward Current (Note 6)		ls	99	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	IDM	396	А	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycl	e = 1%)	Ism	396	А
Avalanche Current, L = 3mH (Note 8)		las	11	А
Avalanche Energy, L = 3mH (Note 8)		Eas	181.5	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	TA = +25°C	PD	2.3	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	54	°C/W
Total Power Dissipation	Tc = +25°C	PD	156	W
Thermal Resistance, Junction to Case (Note 7)		Rejc	0.8	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	100	—		V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS		—	1	μA	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS		—	±100	nA	$V_{GS}=\pm 20V,V_{DS}=0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	VGS(TH)	2.1	—	3.9	V	$V_{DS} = V_{GS}$, $I_D = 250 uA$	
Static Drain-Source On-Resistance	Proven	_	7.2	8.8	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Drain-Source On-nesistance	R _{DS(ON)}		10.5	16	11152	$V_{GS} = 6V, I_D = 5A$	
Diode Forward Voltage	V _{SD}		0.8	1.2	V	$V_{GS} = 0V, I_{S} = 13A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss	—	2085	—			
Output Capacitance	Coss	—	609	—	pF	$V_{DS} = 50V, V_{GS} = 0V$ f = 1MHz	
Reverse Transfer Capacitance	Crss	—	13	—			
Gate Resistance	Rg	—	1.7	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	—	30	—			
Gate-Source Charge	Qgs	—	9.5	—	nC	$V_{DD} = 50V, I_D = 13A, V_{GS} = 10V$	
Gate-Drain Charge	Q _{gd}	—	7.3	—		VGS = 10V	
Turn-On Delay Time	td(on)	_	9.7	_		$\label{eq:VDD} \begin{split} V_{DD} &= 50V, \ V_{GS} = 10V, \\ I_{D} &= 13A, \ R_{g} = 6\Omega \end{split}$	
Turn-On Rise Time	tR	—	13.7	—	20		
Turn-Off Delay Time	td(off)	_	25.1	_	ns		
Turn-Off Fall Time	tF	_	17.3	_			
Reverse Recovery Time	t _{RR}	_	45	—	ns	I _F = 13A, di/dt = 100A/μs	
Reverse Recovery Charge	Qrr	_	68	_	nC	$I_{F} = 10A, u_{V}u_{L} = 100A/\mu S$	

Notes:

Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).

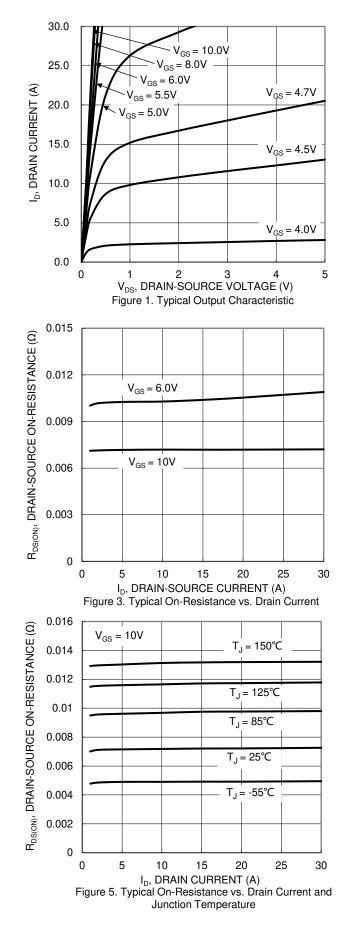
8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

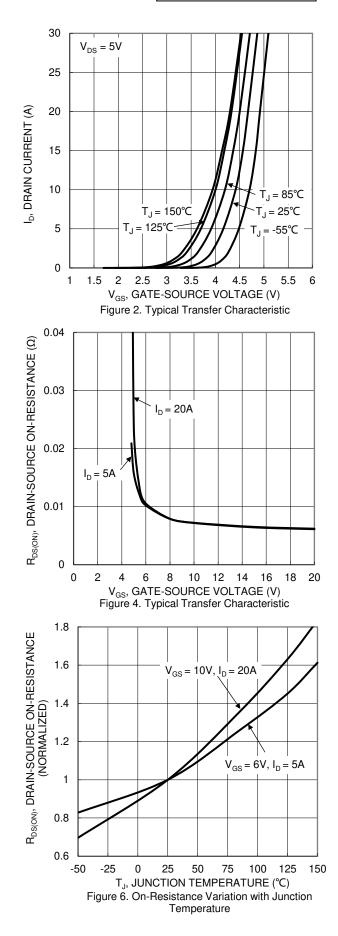
9. Short duration pulse test used to minimize self-heating effect.

10. Guaranteed by design. Not subject to product testing.



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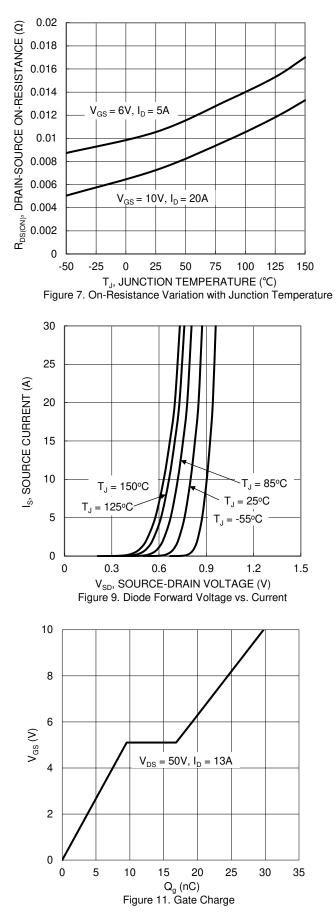


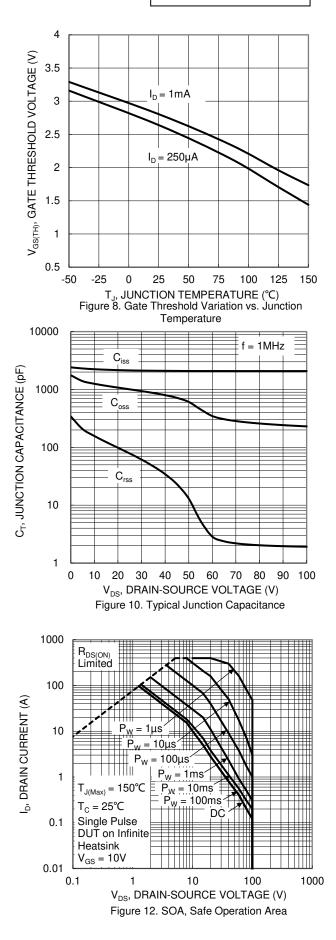


DMT10H9M9SCT Document number: DS43275 Rev. 3 - 2



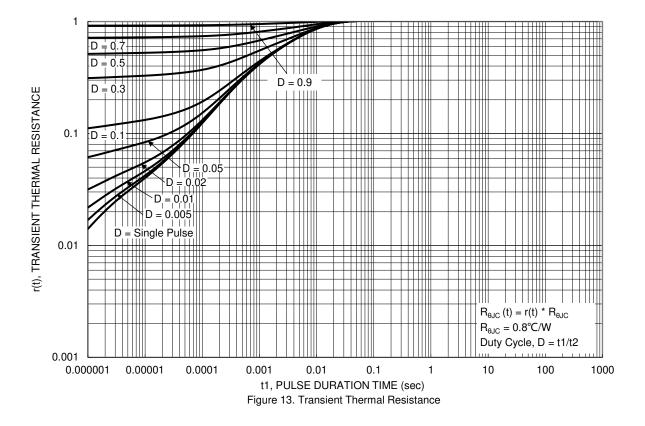
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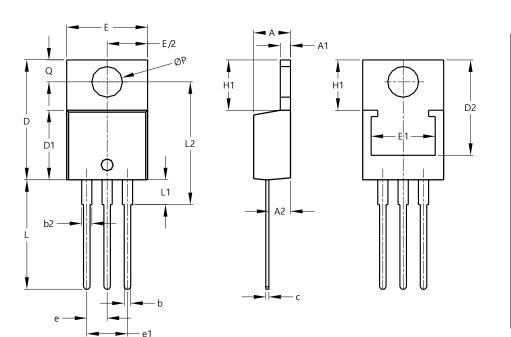






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



TO220AB						
Dim	Min	Max	Тур			
Α	3.56	4.82				
A1	0.51	1.39				
A2	2.04	2.92				
b	0.39	1.01	0.81			
b2	1.15	1.77	1.24			
С	0.356	0.61				
D	14.22	16.51				
D1	8.39	9.01				
D2	11.45	12.87				
е			2.54			
e1			5.08			
Е	9.66	10.66	_			
E1	6.86	8.89	_			
H1	5.85	6.85				
L	12.70	14.73	_			
L1	_	4.42	_			
L2	15.80	17.51	16.00			
Ρ	3.54	4.08	_			
Q	2.54	3.42				
All Dimensions in mm						

TO220AB



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